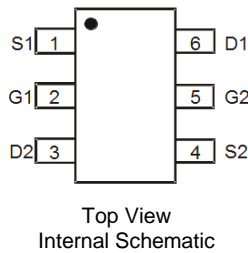


**INTEGRATED RELAY AND INDUCTIVE LOAD DRIVER**
**Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
60V	1.8Ω @ V <sub>GS</sub> = 5V	630mA
	2.4Ω @ V <sub>GS</sub> = 3V	

**Description and Applications**

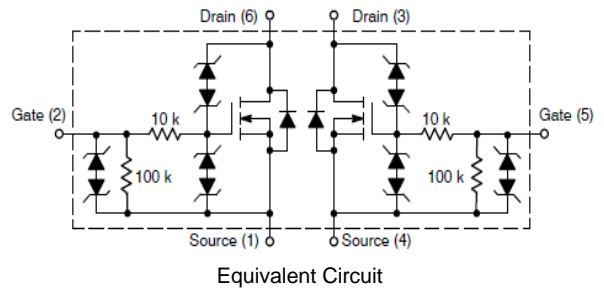
DMN61D8LVTQ provides a single component solution for switching inductive loads such as relays, solenoids, and small DC motors in automotive applications, without the need of a freewheeling diode. DMN61D8LVTQ accepts logic level inputs, thus allowing it to be driven by logic gates, inverters and microcontrollers. It is ideally suited for door, window and antenna relay coils.


**Features and Benefits**

- Provides a reliable and robust interface between sensitive logic and DC relay coils
- Replaces 3 to 4 discrete components enabling PCB footprint to be reduced
- Internal active clamp removes the need for external zener diode
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

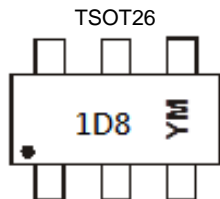
**Mechanical Data**

- Case: TSOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram
- Terminals: Finish – Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.013 grams (Approximate)


**Ordering Information (Note 5)**

Part Number	Case	Packaging
DMN61D8LVTQ-7	TSOT26	3,000/Tape & Reel
DMN61D8LVTQ-13	TSOT26	10,000/Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to [http://www.diodes.com/product\\_compliance\\_definitions.html](http://www.diodes.com/product_compliance_definitions.html).
  5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**


1D8 = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year (ex: D = 2016)  
 M = Month (ex: 9 = September)

**Date Code Key**

Year	2016	2017	2018	2019	2020	2021	2022
Code	D	E	F	G	H	I	J

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V <sub>DSS</sub>	60	V
Gate-Source Voltage			V <sub>GSS</sub>	±12	V
Continuous Drain Current (Note 7)	Steady State	T <sub>A</sub> = +25°C	I <sub>D</sub>	630	mA
		T <sub>A</sub> = +70°C		500	
Maximum Continuous Body Diode Forward Current (Note 7)			I <sub>S</sub>	0.5	A
Single Pulse Drain-to-Source Avalanche Energy (For Relay's Coils/Inductive Loads of 80Ω or Higher) (T <sub>J</sub> Initial = +85°C)			EZ	200	mJ
Peak Power Dissipation, Drain-to-Source (Non repetitive current square pulse 1.0ms duration) (T <sub>J</sub> Initial = +85°C)			PPK	20	W
Load Dump Pulse, Drain-to-Source, R <sub>SOURCE</sub> = 0.5Ω, t = 300ms) (For Relay's Coils/Inductive Loads of 80Ω or Higher) (T <sub>J</sub> Initial = +85°C)			ELD1	60	V
Inductive Switching Transient 1, Drain-to-Source (Waveform: R <sub>SOURCE</sub> = 10Ω, t = 2.0ms) (For Relay's Coils/Inductive Loads of 80Ω or Higher) (T <sub>J</sub> Initial = +85°C)			ELD2	100	V
Inductive Switching Transient 2, Drain-to-Source (Waveform: R <sub>SOURCE</sub> = 4.0Ω, t = 50μs) (For Relay's Coils/Inductive Loads of 80Ω or Higher) (T <sub>J</sub> Initial = +85°C)			ELD3	300	V
Reverse Battery, 10 Minutes (Drain-to-Source) (For Relay's Coils/Inductive Loads of 80Ω or more)			Rev-Bat	-14	V
Dual Voltage Jump Start, 10 Minutes (Drain-to-Source)			Dual-Volt	28	V
ESD Human Body Model (HBM)			ESD	4,000	V

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

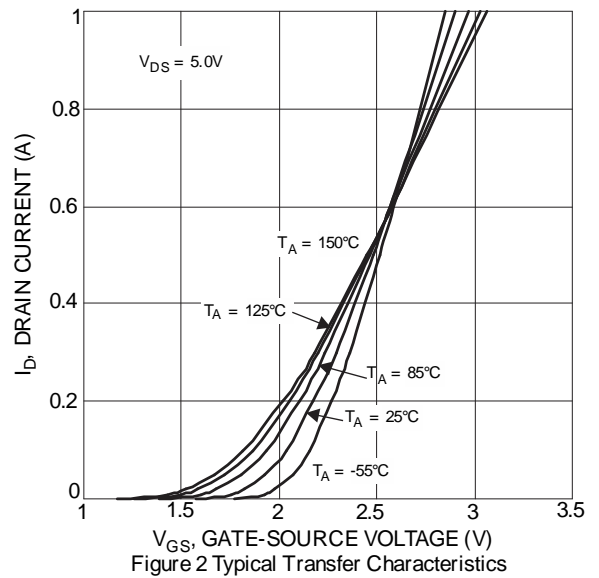
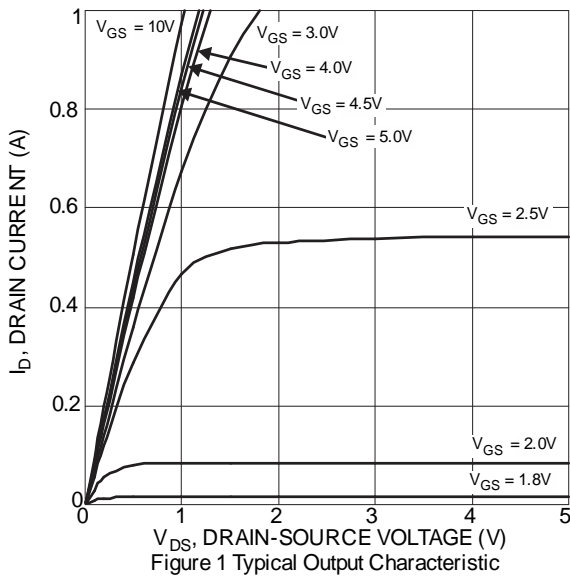
Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 6)		P <sub>D</sub>	820	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>θJA</sub>	154	°C/W
Total Power Dissipation (Note 7)		P <sub>D</sub>	1,090	mW
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	R <sub>θJA</sub>	116	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes: 6. Device mounted on FR-4 PCB, with minimum recommended pad layout.  
7. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. copper, single sided.

**Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 8)</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	60	—	—	V	$V_{GS} = 0\text{V}$ , $I_D = 10\text{mA}$
Zero Gate Voltage Drain Current	$I_{DSS}$	—	—	50 0.5	$\mu\text{A}$	$V_{DS} = 60\text{V}$ , $V_{GS} = 0\text{V}$ $V_{DS} = 12\text{V}$ , $V_{GS} = 0\text{V}$
Gate-Source Leakage	$I_{GSS}$	—	—	$\pm 90$ $\pm 60$	$\mu\text{A}$	$V_{GS} = \pm 5\text{V}$ , $V_{DS} = 0\text{V}$ $V_{GS} = \pm 3\text{V}$ , $V_{DS} = 0\text{V}$
<b>ON CHARACTERISTICS (Note 8)</b>						
Gate Threshold Voltage	$V_{GS(TH)}$	1.3	—	2.0	V	$V_{DS} = V_{GS}$ , $I_D = 1\text{mA}$
Static Drain-Source On-Resistance	$R_{DS(ON)}$	—	1.1	1.8	$\Omega$	$V_{GS} = 5\text{V}$ , $I_D = 0.15\text{A}$
			1.4	2.4		$V_{GS} = 3\text{V}$ , $I_D = 0.15\text{A}$
Forward Transfer Admittance	$ Y_{fs} $	80	—	—	ms	$V_{DS} = 12\text{V}$ , $I_D = 0.15\text{A}$
Diode Forward Voltage	$V_{SD}$	—	—	1.2	V	$V_{GS} = 0\text{V}$ , $I_S = 0.15\text{A}$
<b>DYNAMIC CHARACTERISTICS (Note 9)</b>						
Input Capacitance	$C_{iss}$	—	12.9	—	pF	$V_{DS} = 12\text{V}$ , $V_{GS} = 0\text{V}$ $f = 1.0\text{MHz}$
Output Capacitance	$C_{oss}$	—	17	—	pF	
Reverse Transfer Capacitance	$C_{rss}$	—	0.84	—	pF	
Total Gate Charge	$Q_g$	—	0.74	—	nC	$V_{GS} = 5\text{V}$ , $V_{DS} = 12\text{V}$ , $I_D = 150\text{mA}$
Gate-Source Charge	$Q_{gs}$	—	0.19	—	nC	
Gate-Drain Charge	$Q_{gd}$	—	0.16	—	nC	
Turn-On Delay Time	$t_{D(ON)}$	—	131	—	ns	$V_{DD} = 12\text{V}$ , $V_{GS} = 5\text{V}$
Turn-On Rise Time	$t_R$	—	301	—	ns	
Turn-Off Delay Time	$t_{D(OFF)}$	—	582	—	ns	
Turn-Off Fall Time	$t_F$	—	440	—	ns	

Notes: 8. Short duration pulse test used to minimize self-heating effect.  
9. Guaranteed by design. Not subject to product testing.



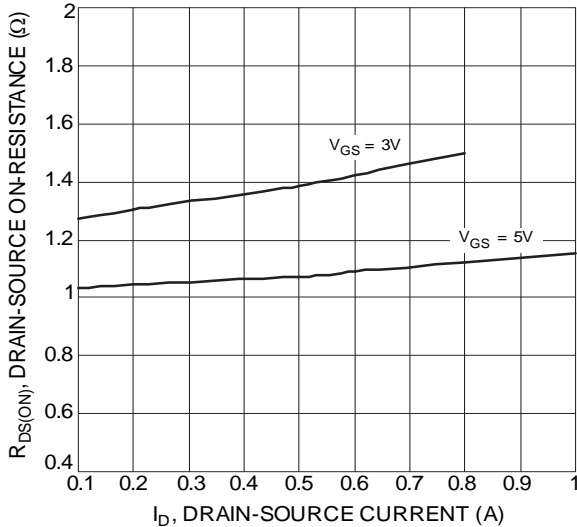


Figure 3 Typical On-Resistance vs. Drain Current and Gate Voltage

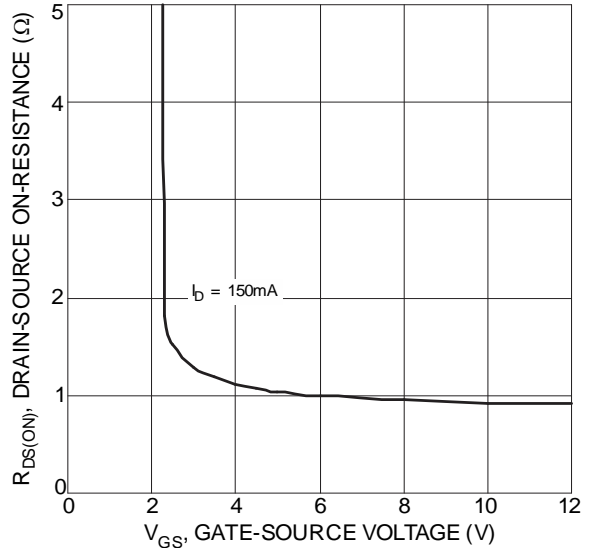


Figure 4 Typical Transfer Characteristic

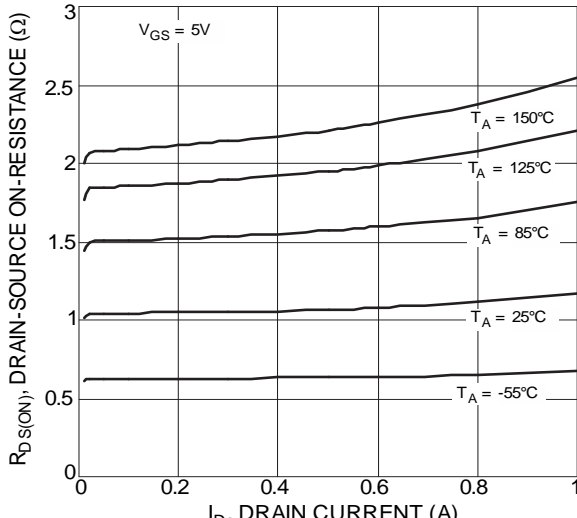


Figure 5 Typical On-Resistance vs. Drain Current and Temperature

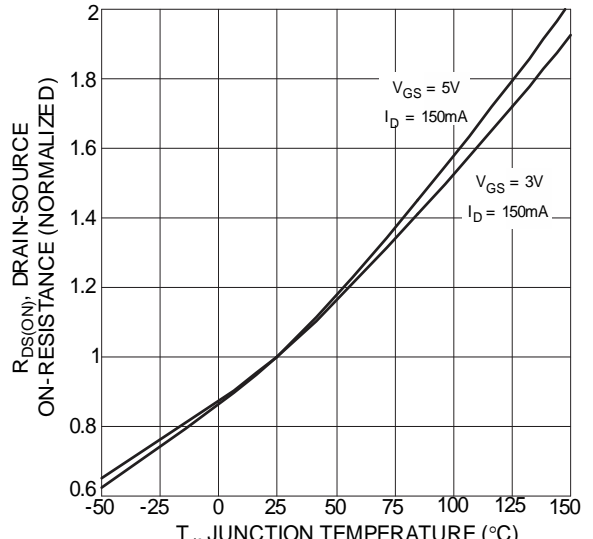


Figure 6 On-Resistance Variation with Temperature

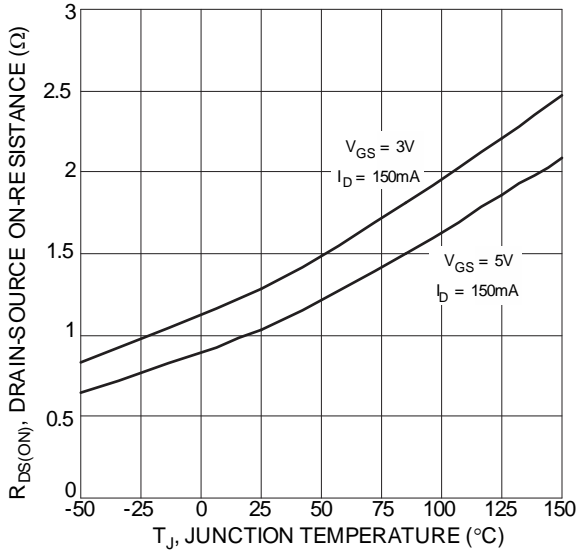


Figure 7 On-Resistance Variation with Temperature

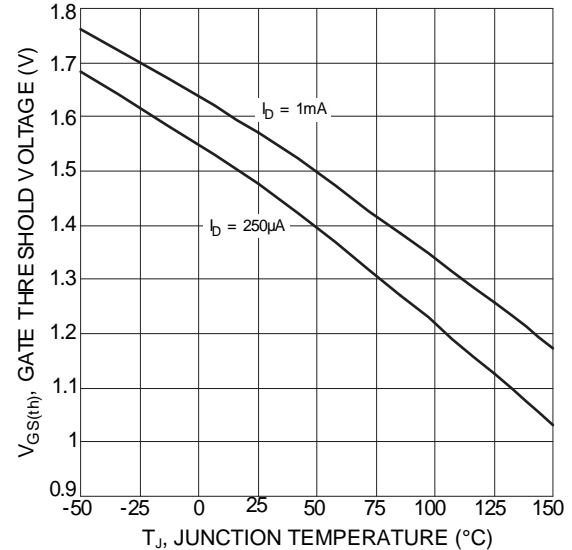


Figure 8 Gate Threshold Variation vs. Junction Temperature

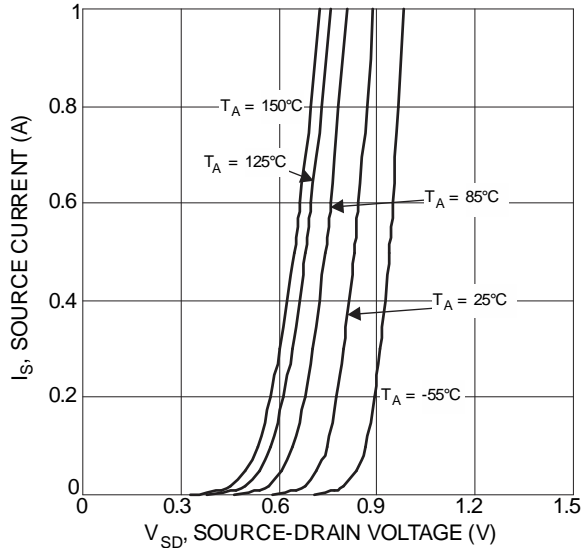


Figure 9 Diode Forward Voltage vs. Current

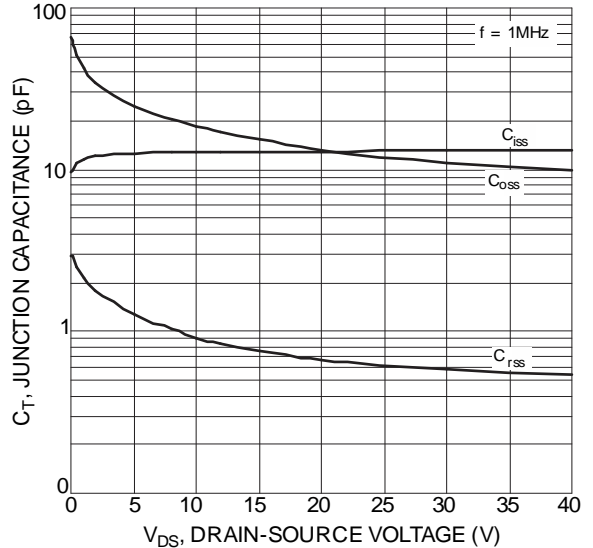


Figure 10 Typical Junction Capacitance

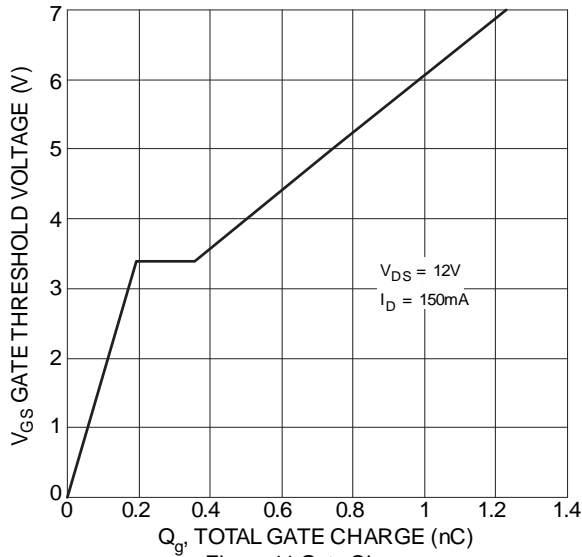


Figure 11 Gate Charge

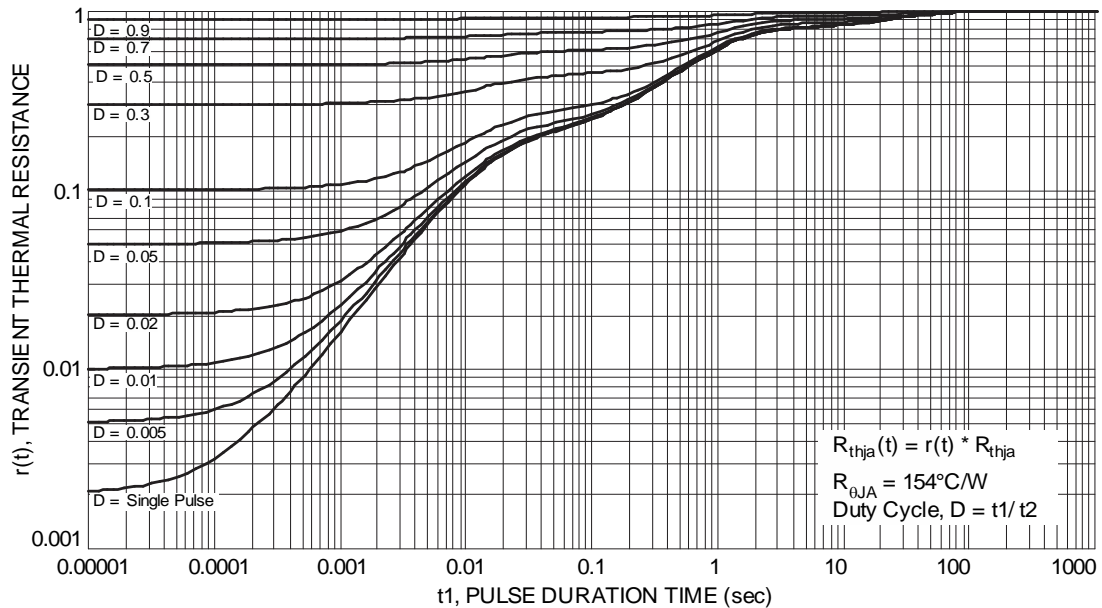
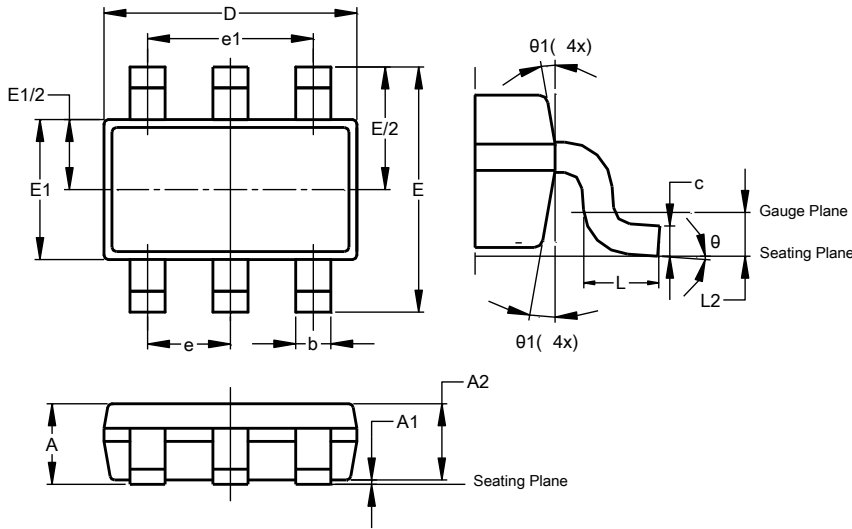


Figure 12 Transient Thermal Resistance

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**TSOT26**

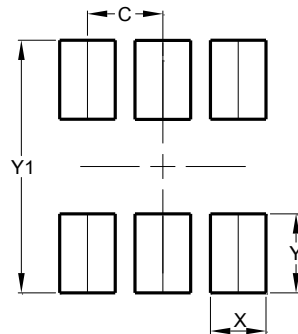


TSOT26			
Dim	Min	Max	Typ
A	–	1.00	–
A1	0.010	0.100	–
A2	0.840	0.900	–
D	2.800	3.000	2.900
E	2.800 BSC		
E1	1.500	1.700	1.600
b	0.300	0.450	–
c	0.120	0.200	–
e	0.950 BSC		
e1	1.900 BSC		
L	0.30	0.50	–
L2	0.250 BSC		
$\theta$	0°	8°	4°
$\theta 1$	4°	12°	–
<b>All Dimensions in mm</b>			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**TSOT26**



Dimensions	Value (in mm)
C	0.950
X	0.700
Y	1.000
Y1	3.199

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